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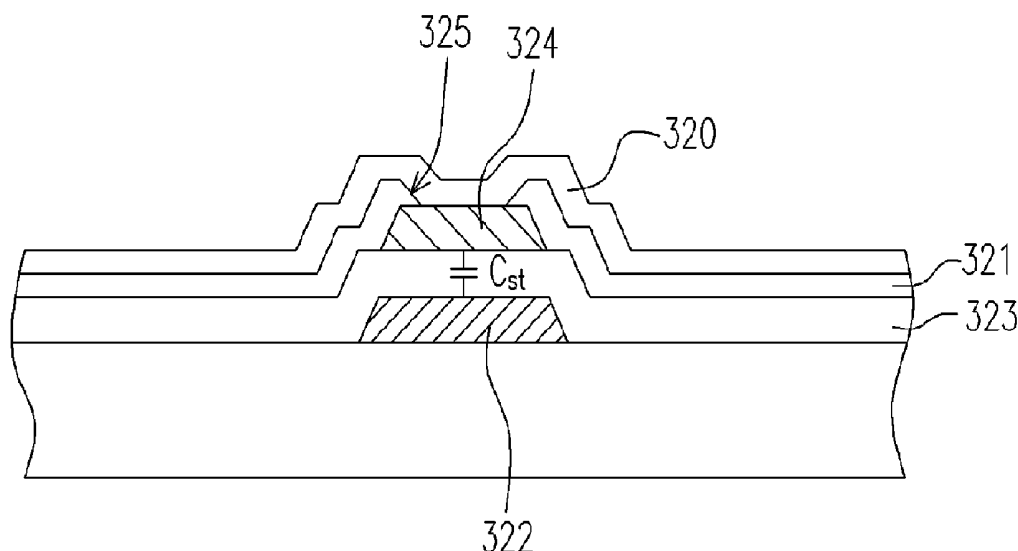
(19) **United States**(12) **Patent Application Publication** (10) **Pub. No.: US 2006/0023136 A1**
Lai (43) **Pub. Date: Feb. 2, 2006**(54) **LIQUID CRYSTAL DISPLAY PANEL, THIN
FILM TRANSISTOR ARRAY AND
CAPACITOR STRUCTURE****Publication Classification**(51) **Int. Cl.**
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(52) **U.S. Cl.** **349/42**(76) **Inventor: Han-Chung Lai, Taoyuan Hsien (TW)**

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**JIANQ CHYUN INTELLECTUAL PROPERTY
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TAIPEI 100 (TW)**(57) **ABSTRACT**(21) **Appl. No.: 10/904,476**(22) **Filed: Nov. 12, 2004**(30) **Foreign Application Priority Data**

Jul. 29, 2004 (TW)..... 93122690

A thin film transistor array comprising a plurality of common lines for providing the storage capacitance of pixels is provided. In particular, each of the common lines comprises a plurality of branches. Wherein, the common line and the branches thereof, and the pixel electrode constitute the storage capacitor. The branches are disposed at pixels where the luminance quality is bad. Therefore, the storage capacitance of the pixels can be enhanced without altering the aperture ratio of the pixels. Accordingly, the performance of the liquid crystal display panel can be improved.



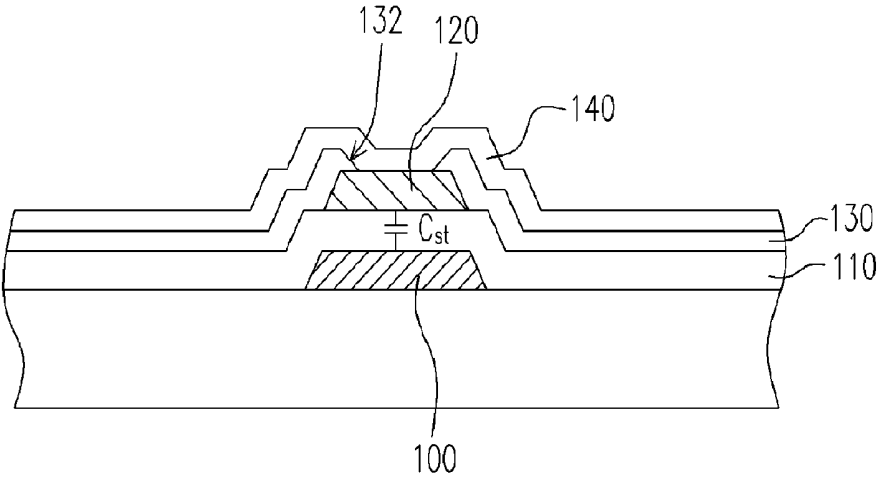


FIG. 1 (RELATED ART)

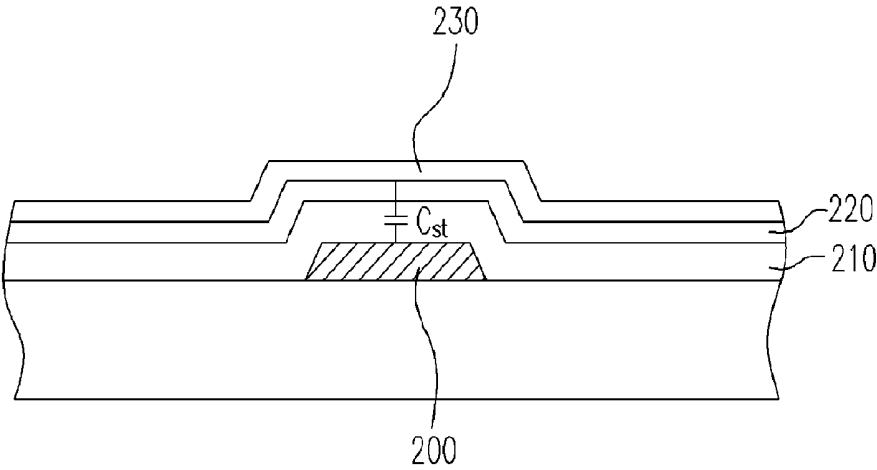


FIG. 2 (RELATED ART)

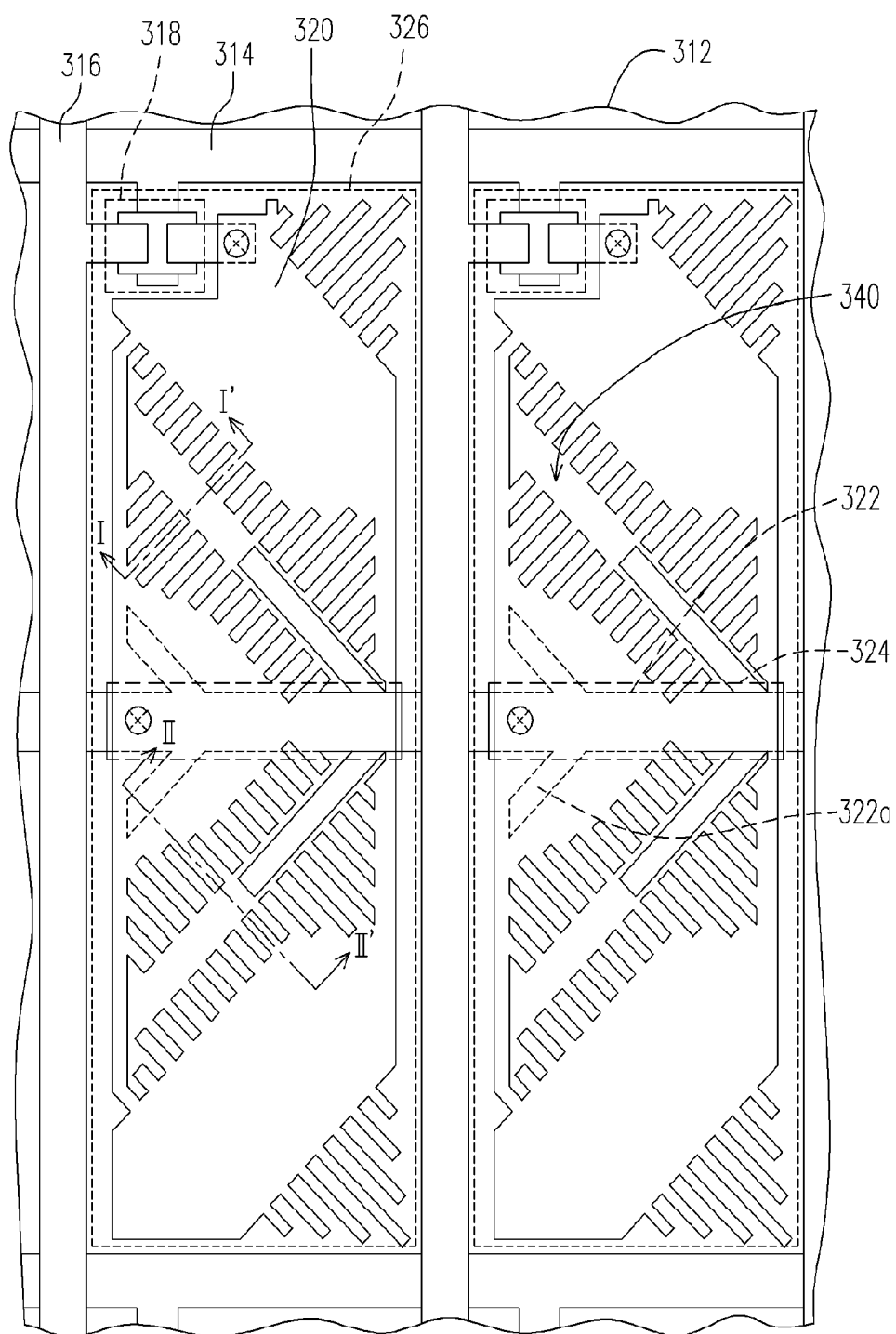


FIG. 3

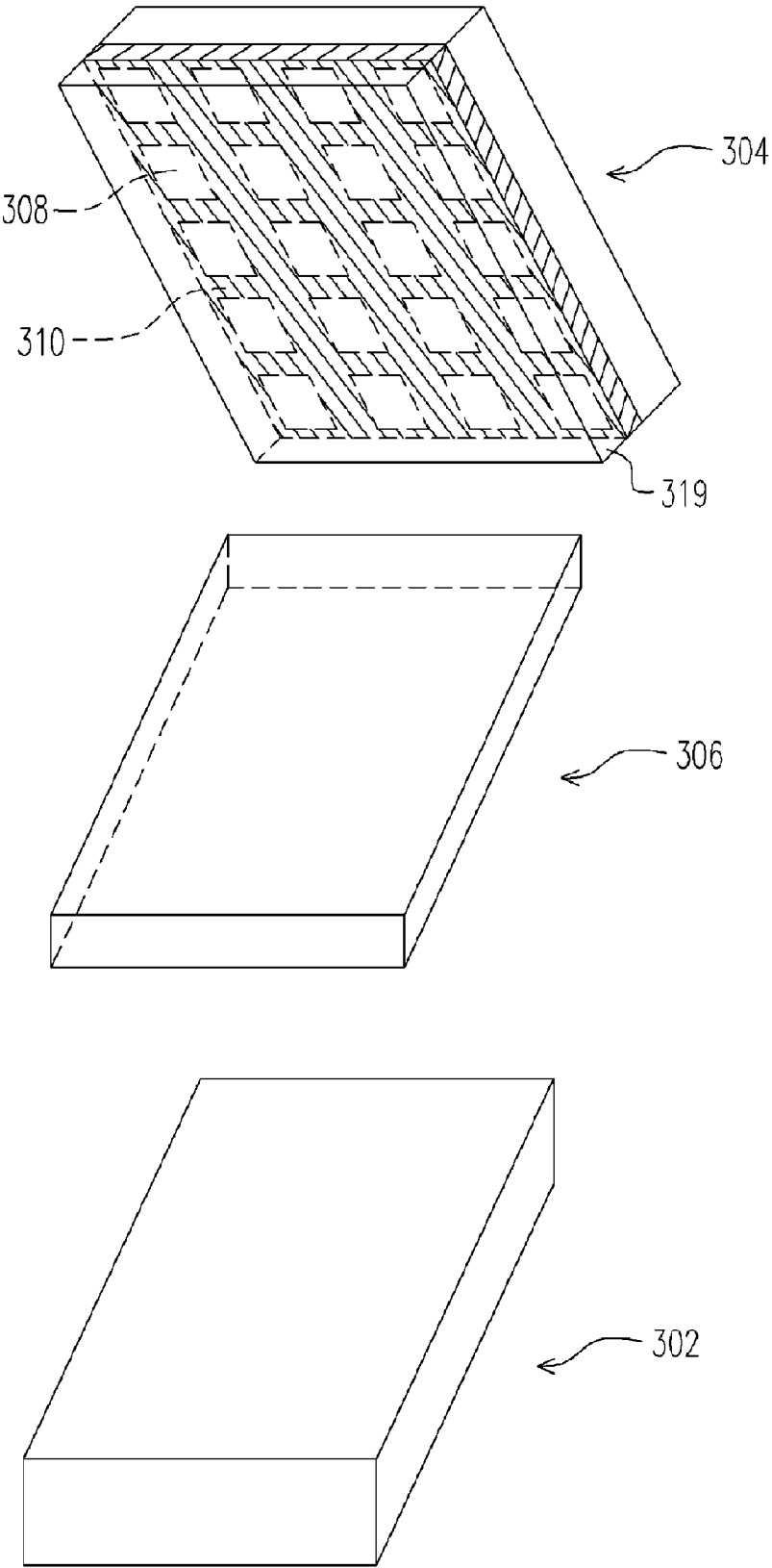
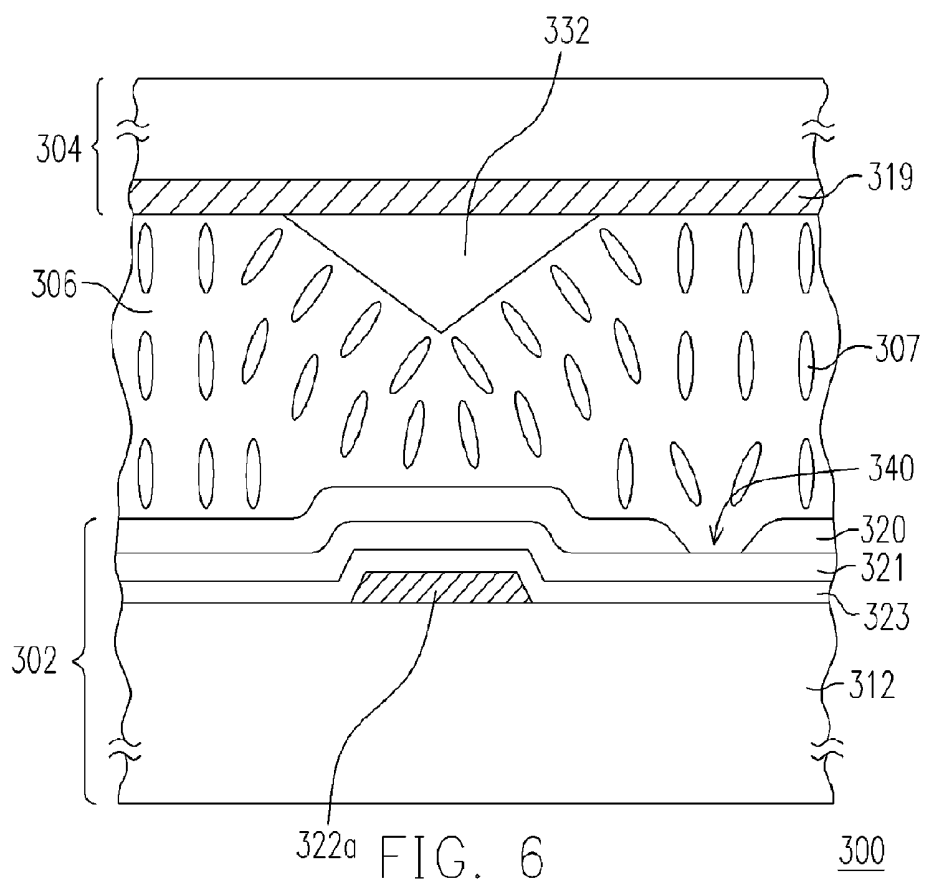
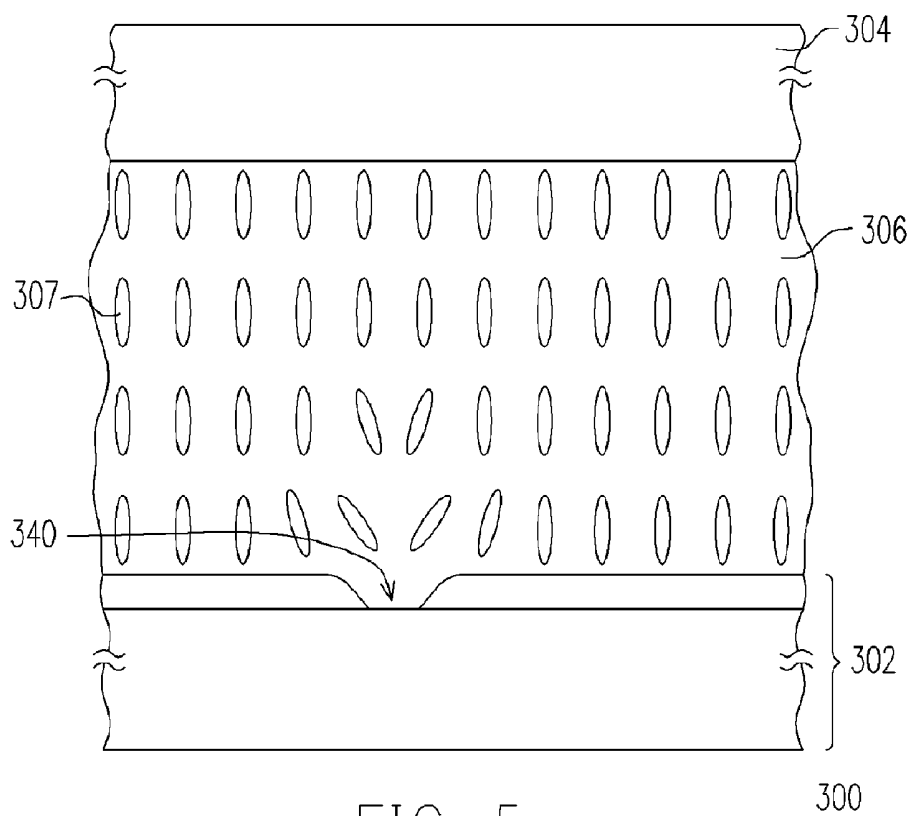


FIG. 4



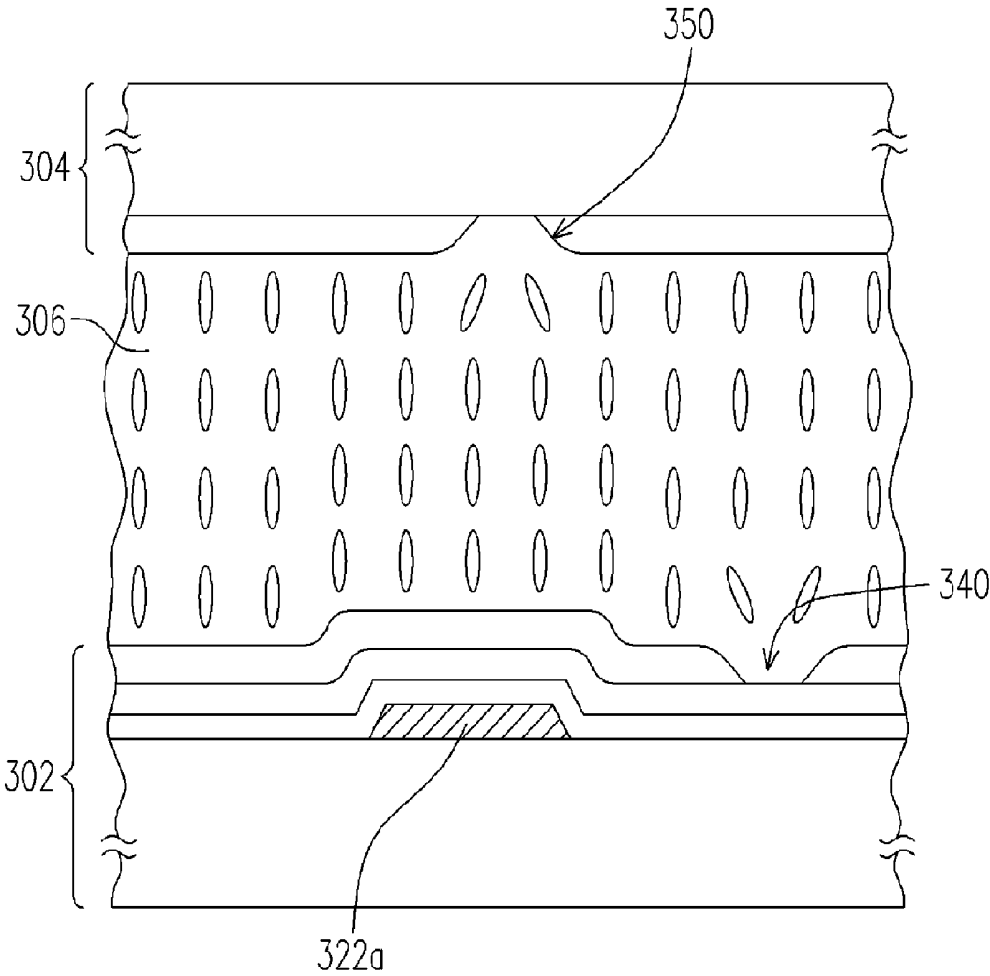


FIG. 7

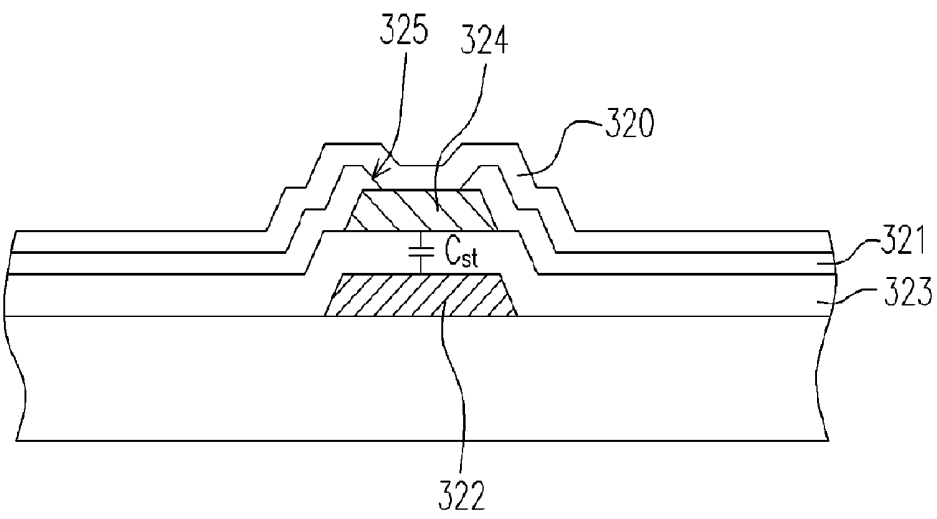


FIG. 8

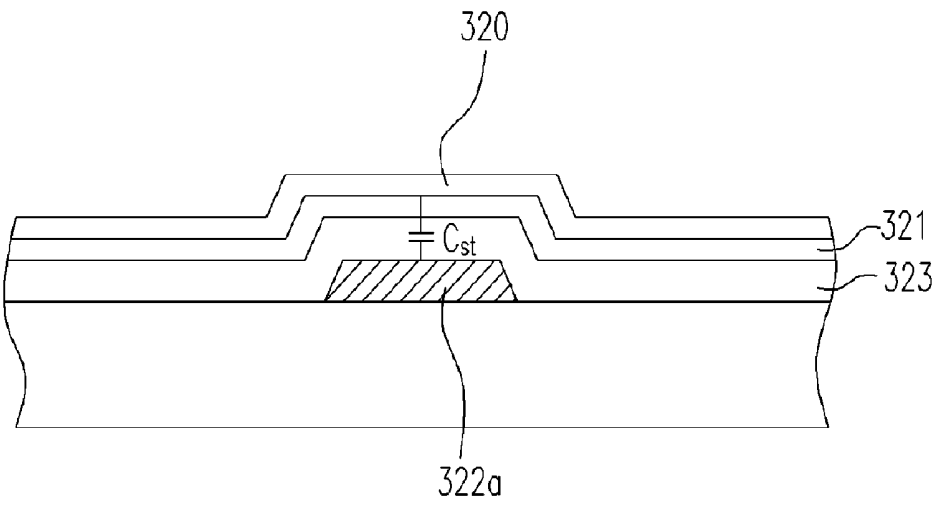


FIG. 9

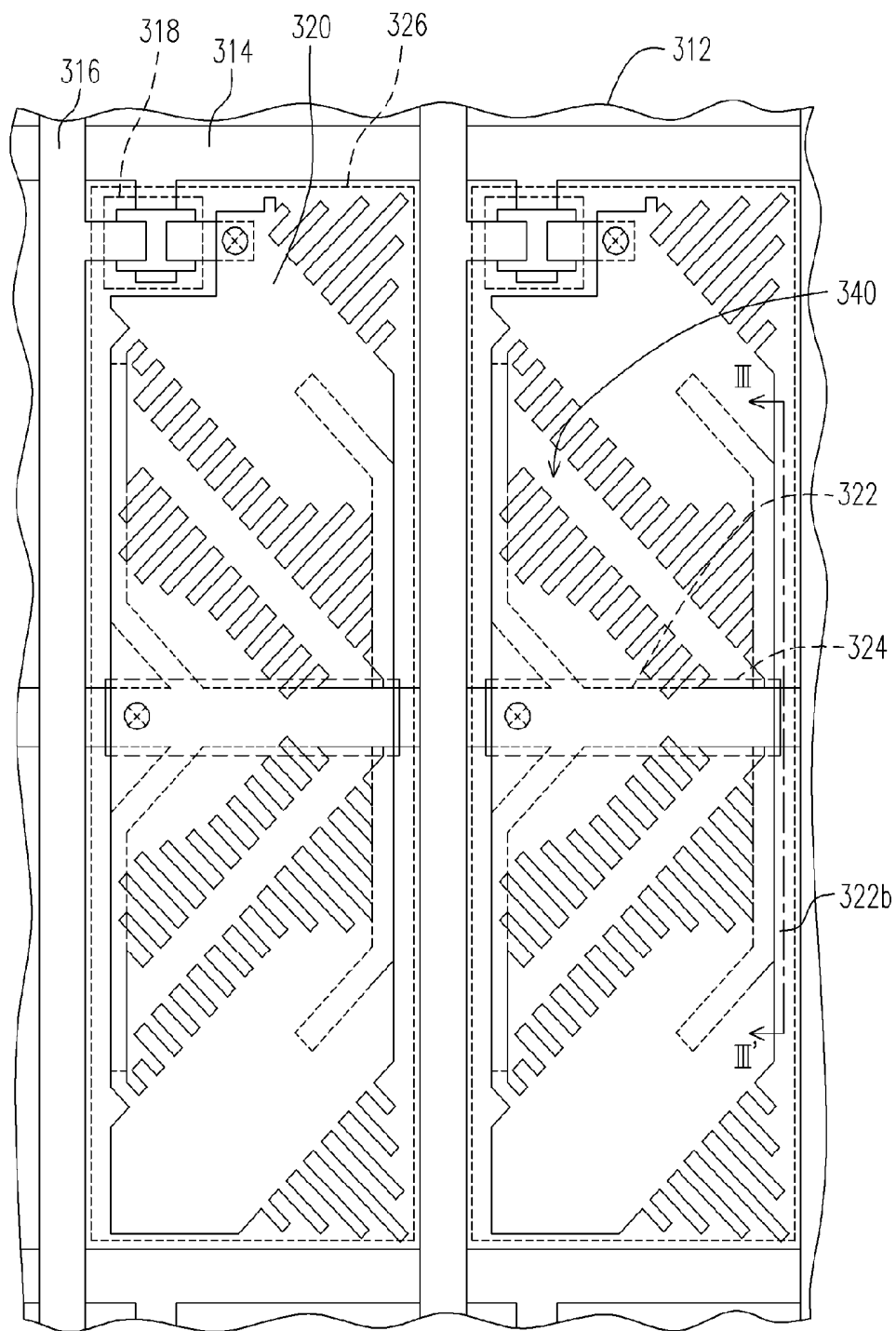


FIG. 10

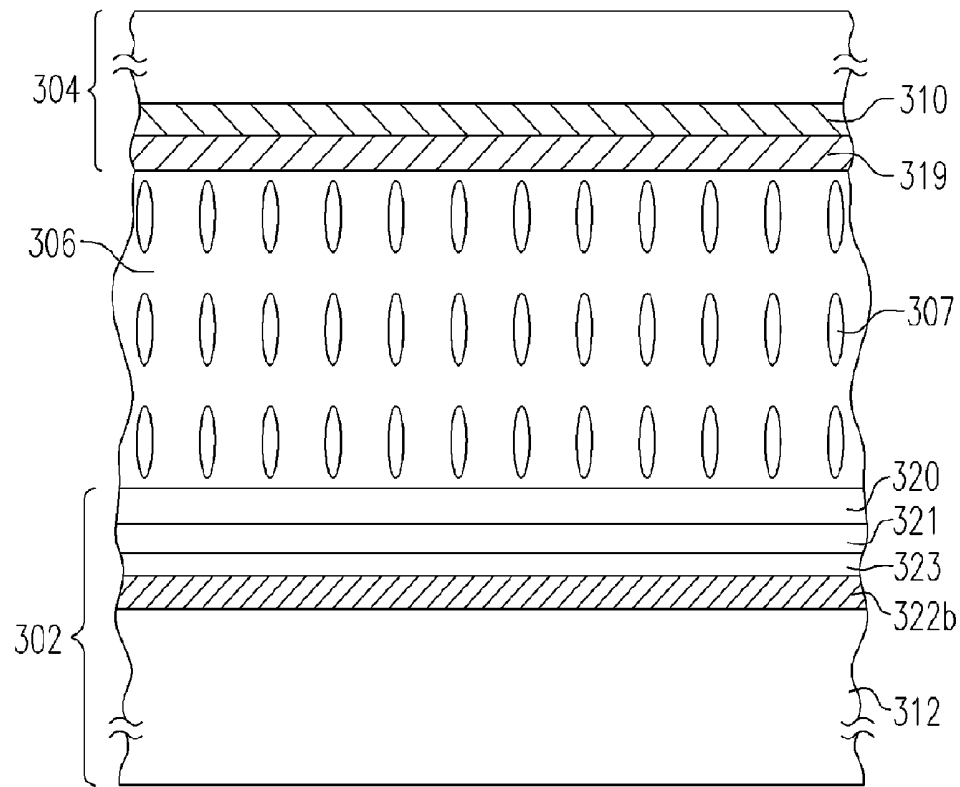


FIG. 11

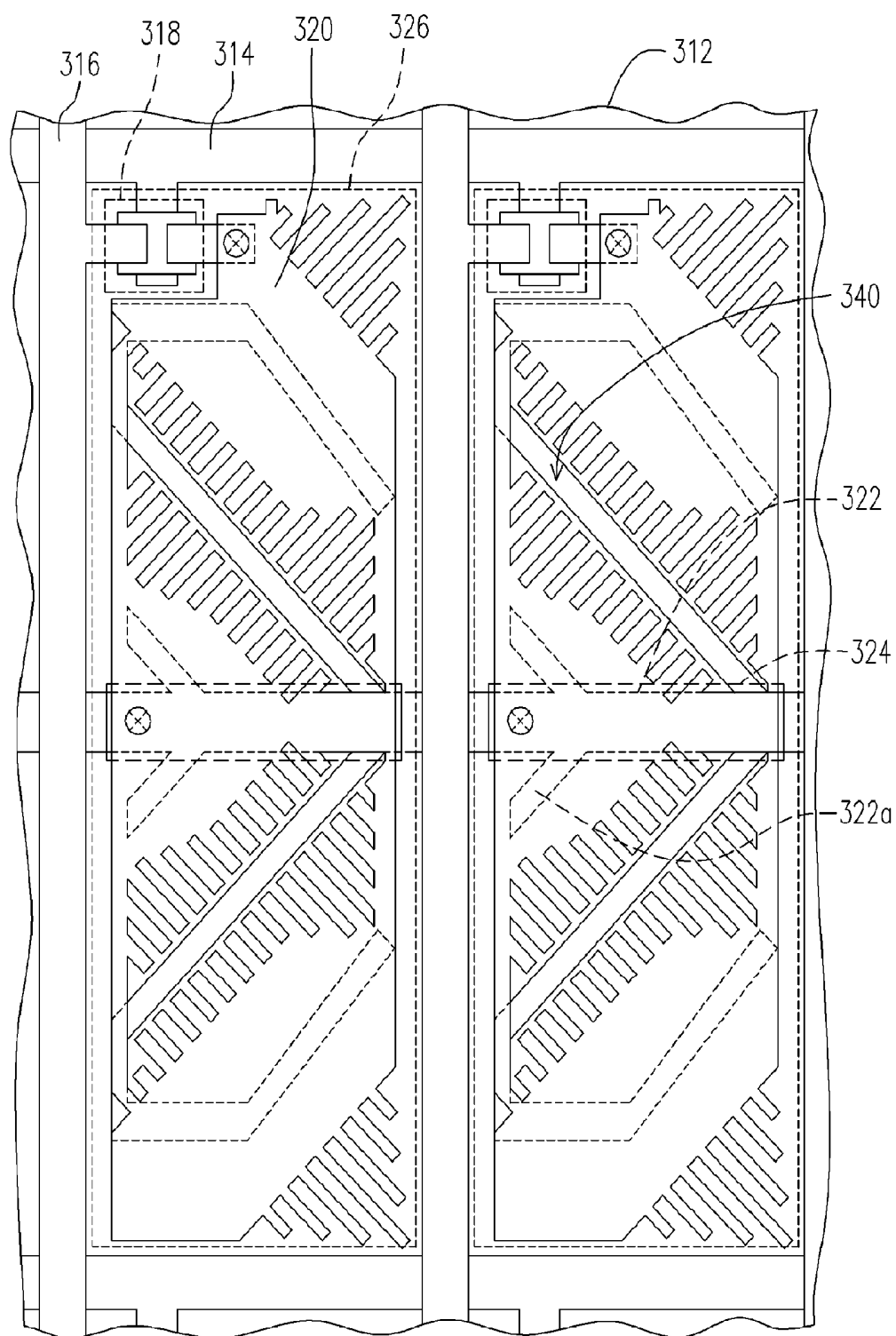


FIG. 12

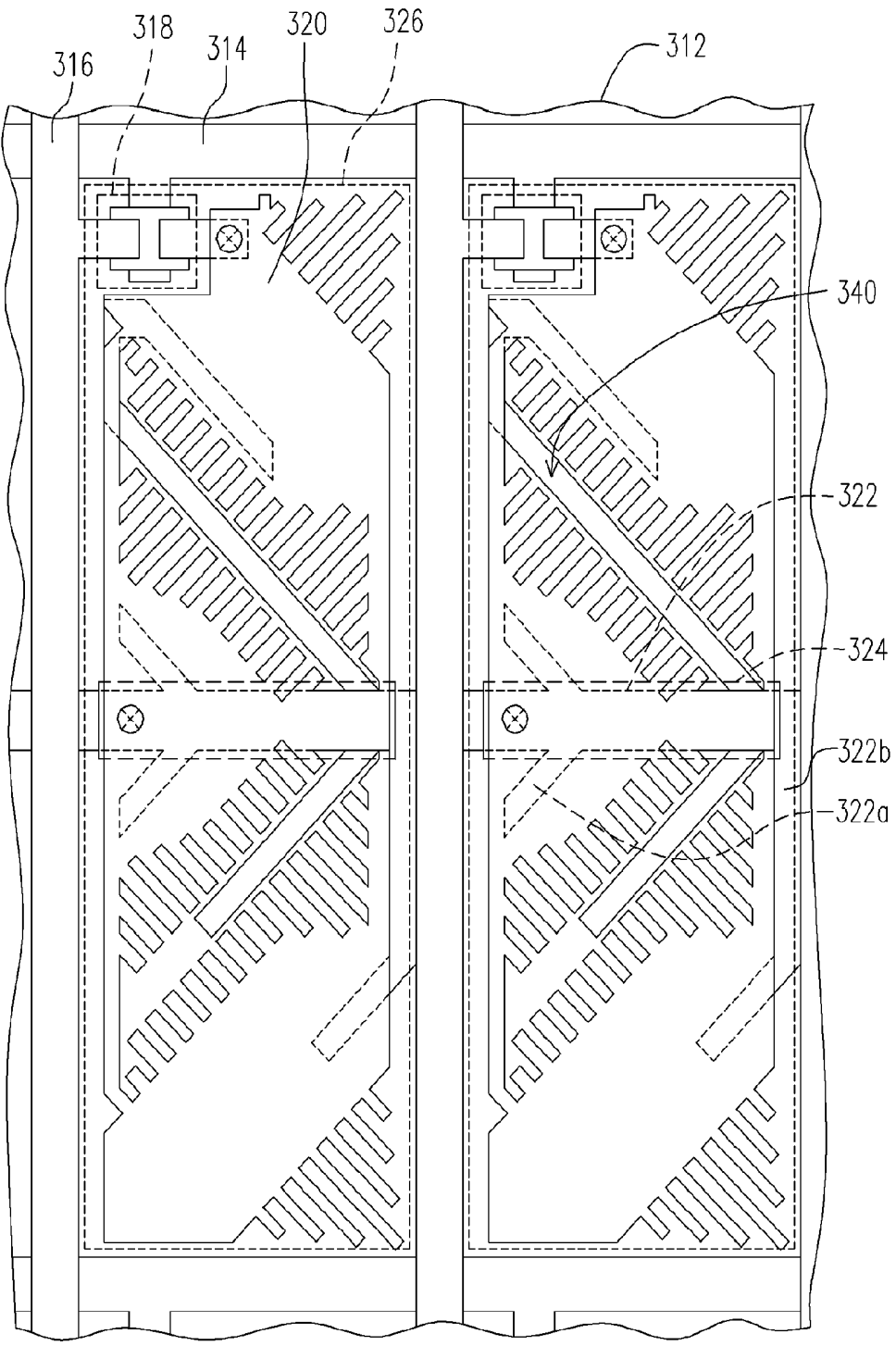


FIG. 13

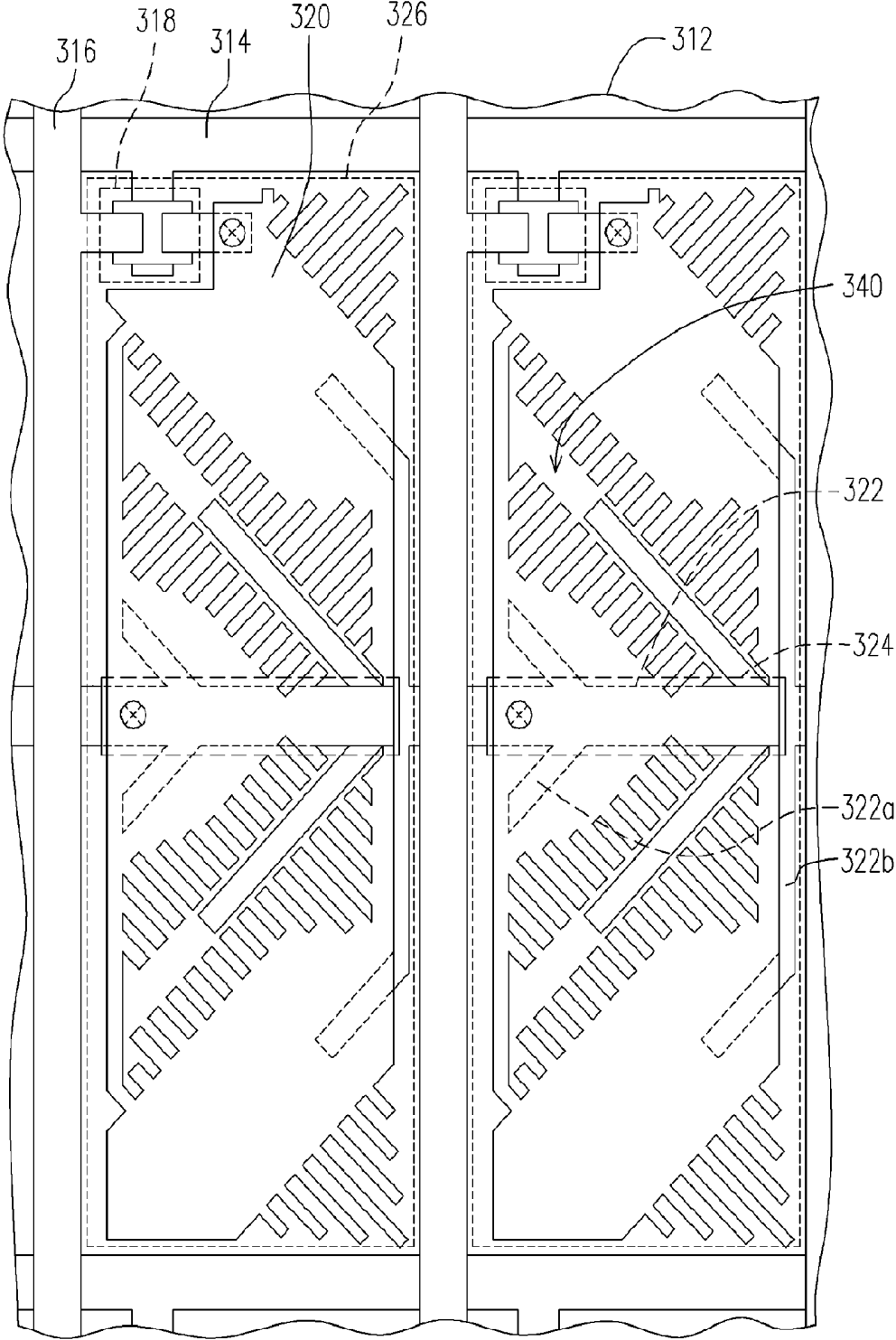


FIG. 14

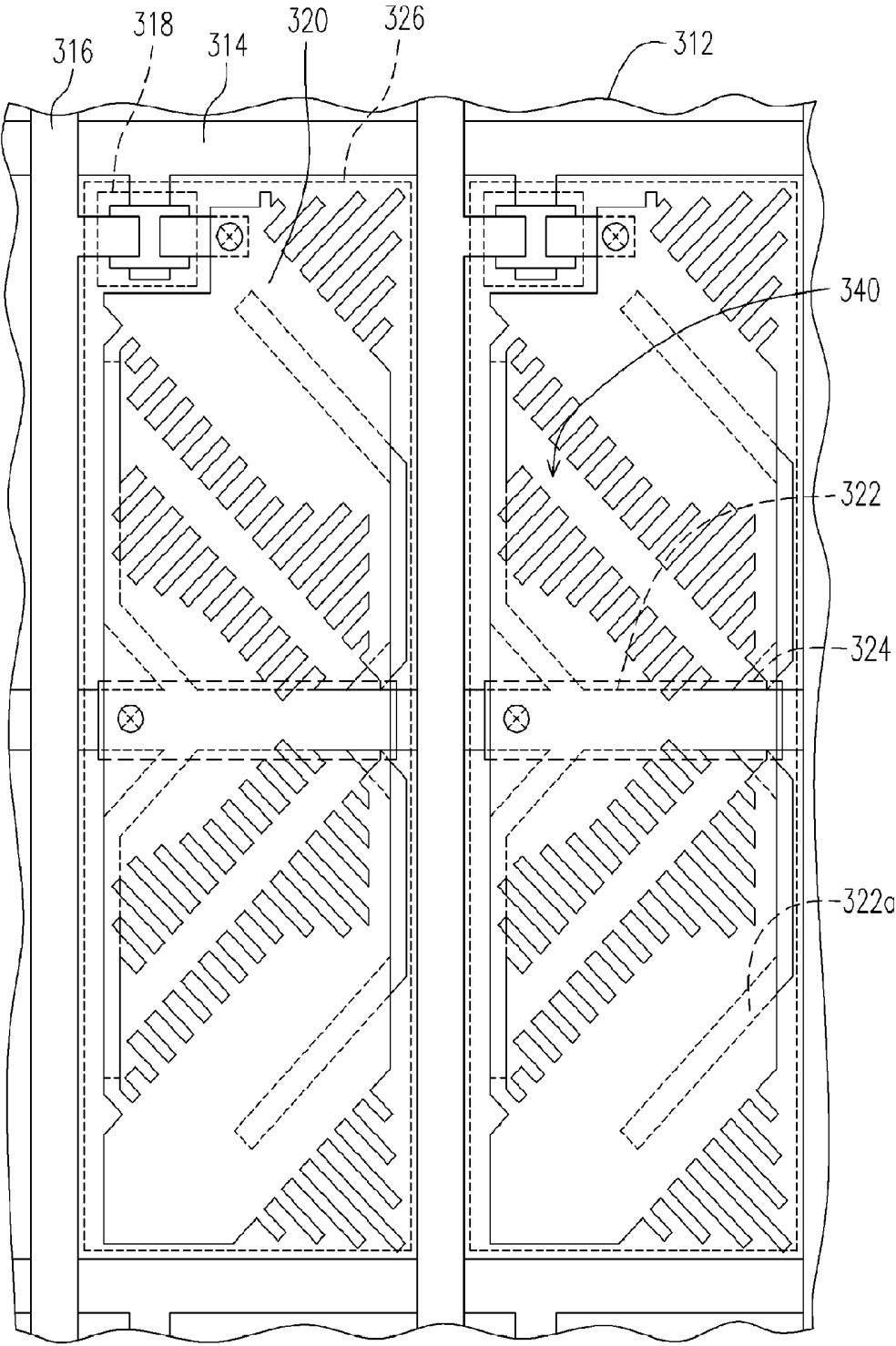


FIG. 15

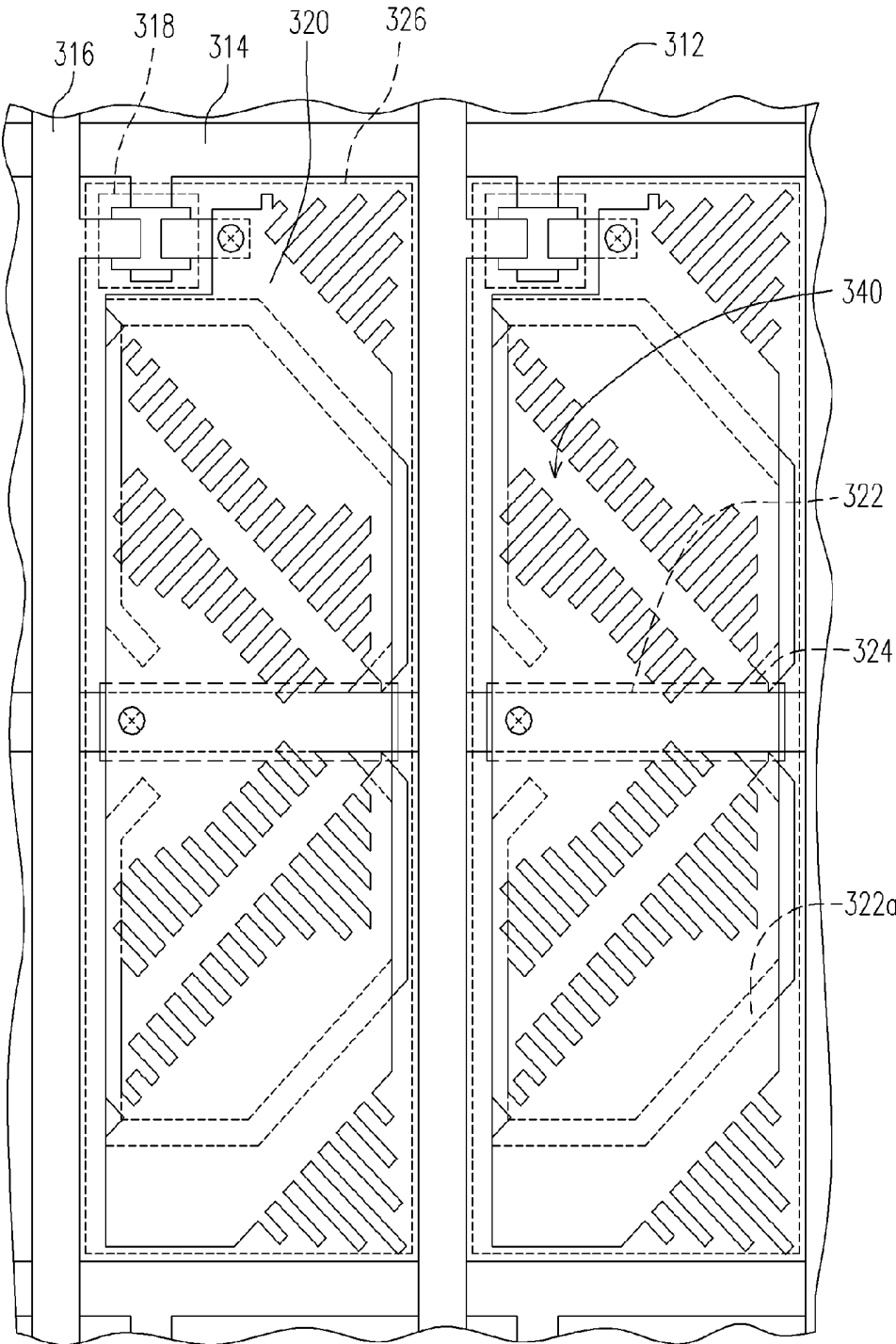


FIG. 16

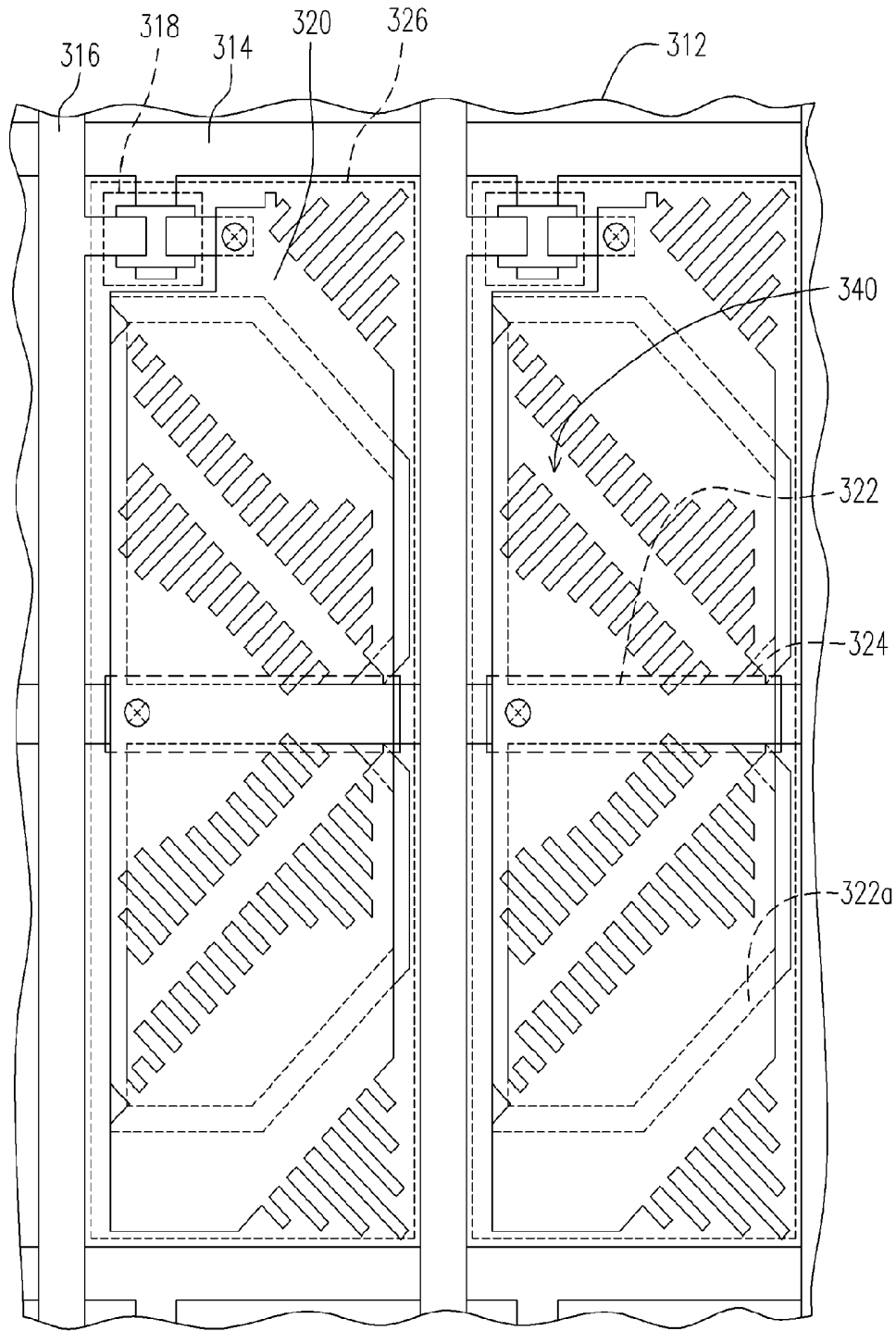


FIG. 17

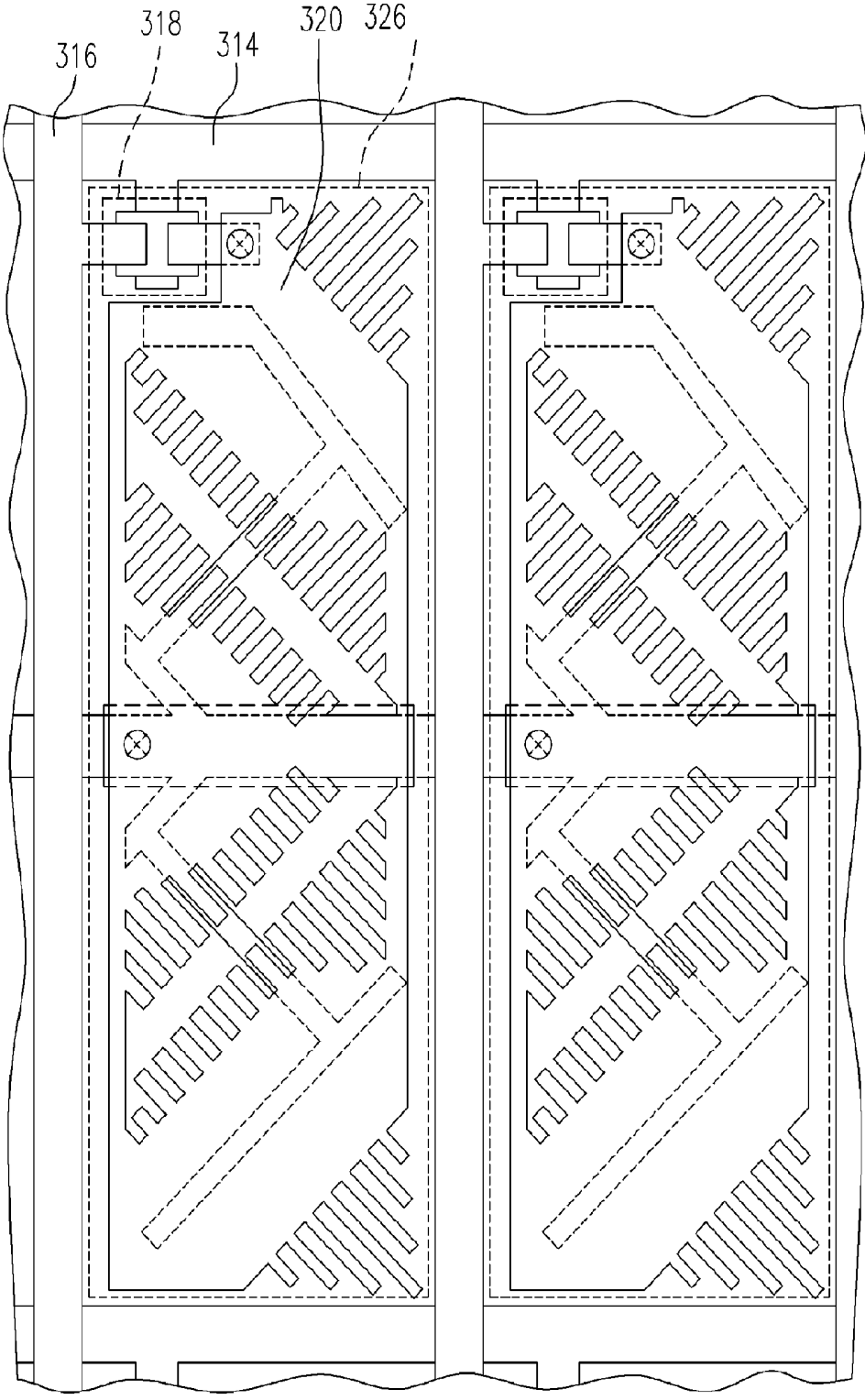


FIG. 18

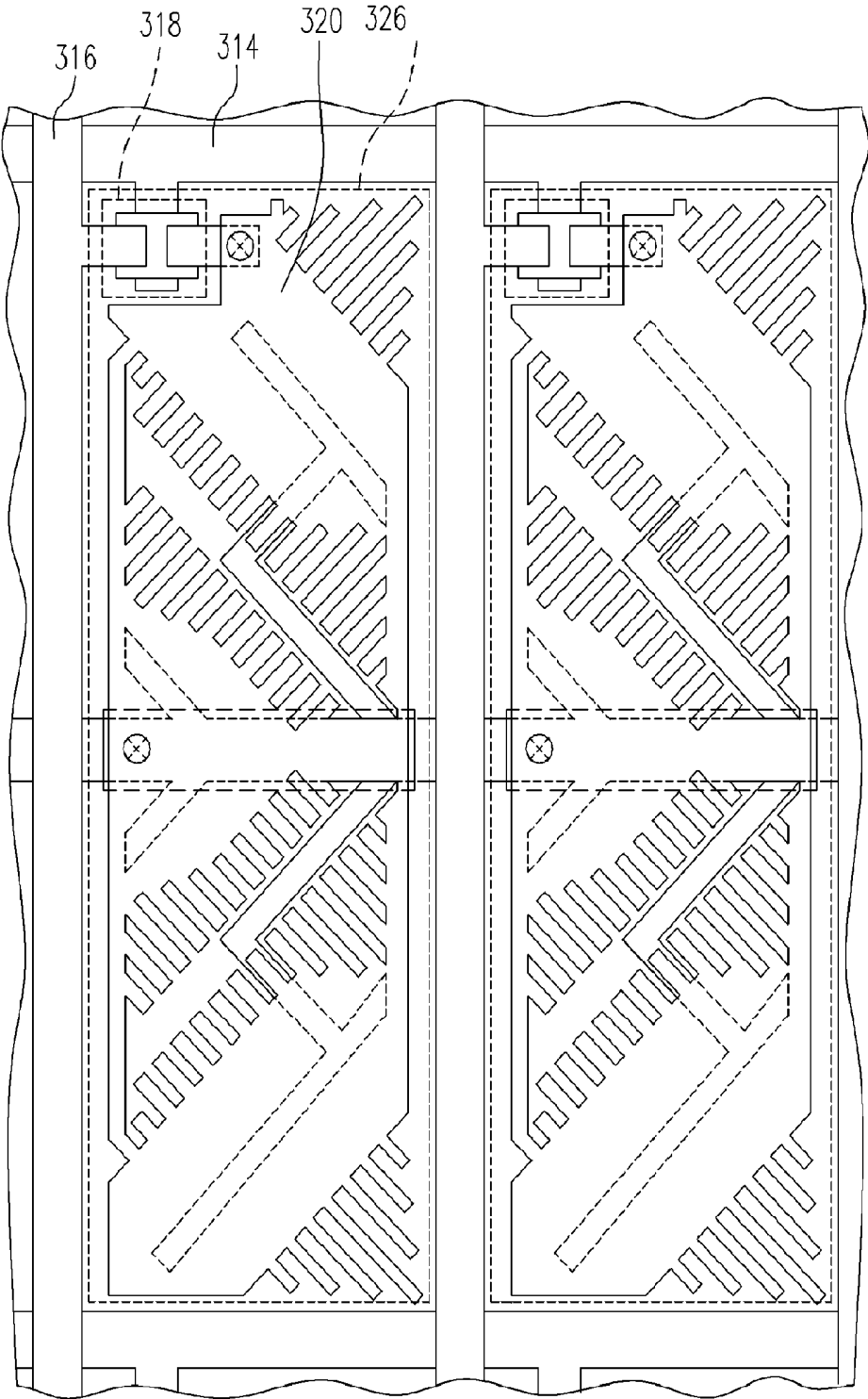


FIG. 19

LIQUID CRYSTAL DISPLAY PANEL, THIN FILM TRANSISTOR ARRAY AND CAPACITOR STRUCTURE

CROSS-REFERENCE TO RELATED APPLICATION

[0001] This application claims the priority benefit of Taiwan application serial no. 93122690, filed Jul. 29, 2004.

BACKGROUND OF THE INVENTION

[0002] 1. Field of the Invention

[0003] The present invention relates to a display apparatus, and more particularly, to a liquid crystal display panel, a thin film transistor array capable of enhancing storage capacitance thereof and a capacitor structure.

[0004] 2. Description of the Related Art

[0005] The rapid development of semiconductor and display technologies has opened the door to a multi-media society. Among display apparatus, thin film transistor liquid crystal displays (TFT-LCDs) have such advantages as high image quality, excellent space-efficiency, low power consumption and non-radiation and have gradually dominated the display market.

[0006] A TFT-LCD mainly comprises a thin film transistor array, a color filter and a liquid crystal layer. Wherein, the thin film transistor array comprises a plurality of thin film transistors arranged in an array and pixel electrodes corresponding thereto. The thin film transistors serve as switches of liquid crystal display units. In order to control the pixel units, scan lines and data lines are used to select specific pixels. By providing proper operating voltages to the pixels, the data corresponding to the pixels are displayed. In addition, a partial area of the said pixel electrode covers the scan line or the common line to form a storage capacitor. Conventional storage capacitors include the metal-insulator-metal (MIM) capacitor and the metal-insulator-ITO (MII) capacitor. What follows are descriptions of these two capacitors.

[0007] FIG. 1 is a cross sectional view showing a conventional MIM storage capacitor. As shown in FIG. 1, the conventional MIM storage capacitor Cst comprises the scan line or common line 100, and the top electrode 120. In the MIM storage capacitor, the scan line or common line 100 and the top electrode 120 are kept isolated by the gate insulator 110. The pixel electrode 140 is electrically connected to the top electrode 120 through the opening 132 in the protection layer 130.

[0008] FIG. 2 is a cross sectional view showing a conventional MII storage capacitor. In FIG. 2, the conventional MII storage capacitor Cst comprises the scan line or common line 200, and the top electrode 230. Compared with the MIM storage capacitor, the MII storage capacitor has such structure that the scan line or common line 220 is isolated from the pixel electrode 230 by the gate insulator 210 and the protection layer 220.

[0009] Generally, higher aperture ratio will bring in better luminance quality. In another aspect, larger capacitance of the capacitor Cst will result in better photo-electric efficiency of the liquid crystal display. However, in the pixel structure of the conventional liquid crystal display, if the

area of the common line is enlarged to increase capacitance Cst, the aperture ratio of the pixel structure will be reduced. To increase the capacitance of the storage capacitor Cst without altering the aperture ratio, the thickness of the gate insulator 210 and/or the protection layer 220 needs to be reduced. However, a thinned-out gate insulator 210 and/or protection layer 220 may damage the reliability of the thin film transistors.

[0010] In addition, particles may fall in the gate insulator and/or the protection layer or cracks may be formed therein due to flaws during the manufacturing process, which will ultimately lead to charge leakage. As a result, the performance of pixels of the display panel is impaired and the display quality is brought down.

SUMMARY OF THE INVENTION

[0011] Accordingly, the present invention is directed to a thin film transistor array for preventing charge leakage of capacitors due to the pollution of particles and for enhancing the capacitance of capacitors to improve the performance of liquid crystal display panels, without altering the aperture ratio and reliability of transistors.

[0012] In the present invention, a thin film transistor array is provided which, along with a color filter and a liquid crystal layer, constitutes a liquid crystal display panel. Wherein, a plurality of patterns is disposed over the color filter. The thin film transistor array comprises a substrate, a plurality of scan lines, a plurality of data lines, a plurality of thin film transistors, a plurality of pixel electrodes and a plurality of common lines. A plurality of pixels is defined by the scan lines and the data lines. The patterns are disposed in a corresponding position to these pixels.

[0013] Following the above paragraph, each of the thin film transistors and each of the pixel electrodes are disposed in a one of the pixels, wherein the thin film transistors are driven by the plurality of scan lines and of the data lines. The plurality of pixel electrodes is electrically connected in response to one of the thin film transistors. Each of the common lines is disposed between two adjacent scan lines. In particular, each of the common lines comprises a plurality of first branches, wherein each of the pixel electrodes covers at least one of the first branches, and each of the first branches is disposed in response to one of the patterns.

[0014] In the present invention, a liquid crystal display panel comprising a color filter, a thin film transistor array and a liquid crystal layer is provided. Wherein, a plurality of patterns is disposed over the color filter. The thin film transistor array comprises a substrate, a plurality of scan lines, a plurality of data lines, a plurality of thin film transistors, a plurality of pixel electrodes and a plurality of common lines. A plurality of pixels is defined by the scan lines and the data lines. The patterns are disposed in a corresponding position to these pixels.

[0015] Following the above paragraph, each of the thin film transistors and each of the pixel electrodes are disposed in a one of the pixels, wherein the thin film transistors are driven by the plurality of scan lines and of the data lines. The plurality of pixel electrodes is electrically connected in response to one of the thin film transistors. Each of the common lines is disposed between two adjacent scan lines. In particular, each of the common lines comprises a plurality

of first branches, wherein each of the pixel electrodes covers at least one of the first branches, and each of the first branches is disposed in response to one of the patterns.

[0016] According to an embodiment of the present invention, the thin film transistor array further comprises a plurality of top electrodes. Each of the top electrodes is disposed between the pixel electrodes and the common lines, and a part of the top electrodes is electrically connected to the corresponding pixel electrodes. In another embodiment, each of the common lines further comprises a plurality of second branches. The second branches are disposed adjacent to the edge of the pixels and in a corresponding position to, for example, black matrixes of the color filter. In still another embodiment, each of the pixel electrodes has a second slit. The first branches, for example, are disposed away from the second slit.

[0017] According to an embodiment of the present invention, the thin film array transistor further comprises a gate insulator disposed over the substrate, covering the scan lines, the common lines and the branches. In addition, the thin film transistor array further comprises a protection layer covering, for example, the data lines and the top electrodes.

[0018] According to an embodiment of the present invention, the patterns, for example, are protrusions or first slits. In another embodiment, the patterns comprise the protrusions and the first slits both.

[0019] In the present invention, a capacitor structure is provided for integrating in a pixel unit. The capacitor structure comprises a substrate, a pixel electrode, a gate insulator and a common line. The common line disposed over the substrate and comprises a plurality of first branches. The gate insulator disposed on the common line. The pixel electrode disposed over the gate insulator.

[0020] According to an embodiment of the present invention, the capacitor structure further comprises a protection layer disposed between the gate insulator and the pixel electrode. In other embodiment of the present invention, the capacitor structure further comprises a top electrode disposed between the gate insulator and the protection layer, wherein the protection layer has an opening, and the top electrode and the pixel electrode is electrically contact via the opening.

[0021] In the present invention, the branches of the common lines are used to increase the capacitance of the capacitors such that the performance of the liquid crystal display panels can be improved. Therefore, even if the area of the common lines is reduced, the capacitance lost due to the reduced area of the common lines can be compensated by the capacitance of capacitors comprising the branches and the pixel electrodes. Therefore, in the present invention, capacitance leakage between the common lines and the pixel electrodes can be prevented.

[0022] The above and other features of the present invention will be better understood from the following detailed description of the embodiments of the invention that is provided in combination with the accompanying drawings.

BRIEF DESCRIPTION OF THE DRAWINGS

[0023] FIG. 1 is a cross sectional view showing a conventional MIM storage capacitor.

[0024] FIG. 2 is a cross sectional view showing a conventional MII storage capacitor.

[0025] FIG. 3 is a schematic top view showing a partial thin film transistor array of an embodiment of the present invention.

[0026] FIG. 4 is a schematic configuration showing a decomposed Multi-Domain Vertical Alignment (MVA) liquid crystal display panel comprising the thin film transistor array in FIG. 3 according to an embodiment of the present invention.

[0027] FIG. 5 is a schematic cross sectional view showing the MVA liquid crystal display panel in FIG. 4.

[0028] FIGS. 6 and 7 are schematic cross sectional views showing the MVA liquid crystal display panel in FIG. 4 according to two different embodiments of the present invention.

[0029] FIG. 8 is a schematic cross sectional view showing a metal-insulator-metal (MIM) storage capacitor structure according to an embodiment of the present invention.

[0030] FIG. 9 is a schematic cross sectional view showing a metal-insulator-ITO (MII) storage capacitor structure according to an embodiment of the present invention.

[0031] FIG. 10 is a schematic top view showing a thin film transistor array according to another embodiment of the present invention.

[0032] FIG. 11 is a schematic cross sectional view along III-III' in FIG. 10.

[0033] FIGS. 12-19 are configurations showing thin film transistor arrays according to the other embodiments of the present invention.

DESCRIPTION OF THE EMBODIMENTS

[0034] In the present invention, the common lines with the branches are used to enhance capacitance. Wherein, these branches of the common lines are disposed in corresponding positions to pixels where the luminance quality is bad to reduce the impact on the aperture ratio. What follows are descriptions of some embodiments in the present invention.

[0035] FIG. 3 is a schematic top view showing a partial thin film transistor array according to an embodiment of the present invention. FIG. 4 is a schematic configuration showing a decomposed Multi-Domain Vertical Alignment (MVA) liquid crystal display panel comprising the thin film transistor array in FIG. 3 according to an embodiment of the present invention. As shown in FIG. 4, the thin film transistor array 302, the color filter 304 and the liquid crystal layer 306 constitute the MVA liquid crystal display panel 300. Wherein, the liquid crystal layer 306 comprises a plurality of liquid crystal molecules (not shown). The color filter 304 comprises a plurality of color filter films 308, a black matrix 310 and a common electrode 319, and the common electrode 319 has patterns for changing the electrically field formed thereon (not shown in FIG. 4).

[0036] Referring to FIG. 3, the thin film transistor array 302 comprises a substrate 312, a plurality of scan lines 314, a plurality of data lines 316, a plurality of thin film transistors 318, a plurality of pixel electrodes 320 and a plurality of common lines 322. Wherein, the data lines 316 and the

scan lines **314** are disposed over the substrate **312** and divide the substrate **312** into a plurality of pixels **326**. The thin film transistors **318** and the pixel electrodes **320** are located in the pixels **326**, and the thin film transistors **318** are driven by the data lines **316** and the scan lines **314**. The pixel electrodes **320** are electrically connected to the thin film transistors **318** corresponding thereto. Wherein, the material of pixel electrodes **320** can comprise indium tin oxide (ITO), indium zinc oxide (IZO) or other transparent conductive material. In particular, as shown in **FIGS. 3 and 5**, a plurality of second slits **340** are formed on the pixel electrodes **320** of the thin film transistor array **302** to change the electrical field in this area. Therefore, the orientation of the liquid crystal molecules adjacent to the second slit **340** can be changed to extend the view angle of the display panel.

[0037] In **FIG. 3**, the common lines **322** are disposed over the substrate **312**. The material of the common lines **322** can be metal. It should be noted that each of the common lines **322** comprises a plurality of the first branches **322a** for enhancing capacitance. Further, each of the pixel electrodes **320** covers at least one first branches **322a** which is disposed in the pixel area **326** where the luminance quality is bad. As a result, the impact on aperture ratio can be reduced. As shown in **FIGS. 6 and 7**, the common electrode **319** of the color filter **304** comprises patterns formed thereon. The patterns, for example, are alignment protrusion **332** and/or first slit **350**. In this embodiment, the first branches **322a** is disposed in a corresponding position to the alignment protrusion **332**, as shown in **FIG. 6**, or to the first slit **350**, as shown in **FIG. 7**. Alternatively, the position of the first branches **322a** may be partially corresponding to the alignment protrusion **332** and partially corresponding to the first slit **350**. One of ordinary skill in the art can refer to **FIGS. 6 and 7** and understand the possible structures and arrangements, so additional drawings are not provided herein.

[0038] In the MVA liquid crystal display panel **300**, the area of the common line **322** can be made smaller than that of the conventional common line **100** as shown in **FIG. 1**, such that capacitance leakage of the storage capacitor Cst due to the pollution of particles can be prevented.

[0039] Please refer to **FIG. 3**, wherein top electrode **324** can also be disposed between the pixel electrode **320** and the common line **322**. The top electrode **324** and the data lines **316** can be formed in the same process. The protection layer **321** covers the data lines **316** as well as the top electrode **324**. The pixel electrode **320** is electrically connected to the top electrode **324** through the opening **325** in the protection layer **321**, as shown in **FIG. 8**. Accordingly, the common line **322**, the protection layer **321** and the top electrode **324** constitute a metal-insulator-metal (MIM) capacitor structure with storage capacitance Cst. On the other hand, if the top electrode **324** does not cover the first branches **322a**, then the first branches **322a**, the protection layer **321**, the gate insulator **323** and the pixel electrode **320** constitute a metal-insulator-ITO (MII) capacitor structure with storage capacitance Cst, as shown in **FIG. 9**. Further, if the top electrode **324** covers the first branches **322a**, then the first branches **322a**, the protection layer **321** and the top electrode **324** constitute a MIM capacitor structure, as shown in **FIG. 8**.

[0040] In other embodiments, each of the common lines **322** may further comprise a plurality of second branches **322b**. The second branches **322b** are disposed in the pixels

326 where the luminance quality is bad. They can be disposed, for example, in areas adjacent to the edge of the pixels **326**, as shown in **FIG. 10**. Alternatively, the second branches **322b** can be totally or partially disposed in the pixel electrodes **326**. They can also be disposed in areas corresponding to the black matrixes **310** of the color filter **304**, as shown in **FIG. 11**.

[0041] It should be noted that the dispositions of the first branches **322a** and the second branches **322b** of the common lines **322** are not limited. As shown in **FIGS. 12-19**, the first branches **322a** or the second branches **322b** of the common lines **322** can be disposed in various patterns. In some embodiments shown in **FIGS. 15-17**, the first branches **322a** or the second branches **322b** are disposed away from the second slit **340**.

[0042] Accordingly, in the present invention, the branches of the common lines are used to enhance the capacitance of the capacitors in the liquid crystal display panels. Therefore, even if the area of the common lines is reduced, the capacitance lost due to the reduced area of the common lines can be compensated by adding branches. Therefore, in the present invention, the area of the common lines is reduced to prevent the capacitance leakage of the capacitors. It should be noted that when the capacitance leakage occurs at the branches of the common lines, the branches which cause the leakage can be cut off in a repairing process. Accordingly, the yield of the liquid crystal display panel can be improved.

[0043] In one embodiment of the present invention, the branches of the common lines are disposed in pixels where the luminance quality is bad. Accordingly, the disposition of the branches in the pixels will not alter the aperture ratio. In other words, in the present invention, the capacitance of the pixels is enhanced without altering the aperture ratio. Accordingly, the liquid crystal display panel of the present invention has the desired aperture ratio and the desired capacitance so the performance of the liquid crystal display panel can be improved.

[0044] Although the present invention has been described in terms of exemplary embodiments, it is not limited thereto. Rather, the appended claims should be constructed broadly to include other variants and embodiments of the invention which may be made by those skilled in the field of this art without departing from the scope and range of equivalents of the invention.

What is claimed is:

1. A thin film transistor array which, along with a color filter and a liquid crystal layer, constitutes a liquid crystal display panel, wherein a plurality of patterns are disposed beneath the color filter, the thin film transistor array comprising:

- a substrate;
- a plurality of scan lines disposed over the substrate;
- a plurality of data lines disposed over the substrate, wherein a plurality of pixels are defined by the scan lines and the data lines;
- a plurality of thin film transistors disposed on the substrate, wherein each of the thin film transistors is disposed in one of the pixels;

- a plurality of pixel electrodes disposed over the substrate, wherein each of the pixel electrodes is disposed in one of the pixels and electrically connected in response to one of the thin film transistors; and
- a plurality of common lines disposed over the substrate, wherein each of the common lines is disposed between two adjacent scan lines, each of the common lines comprising a plurality of first branches, wherein each of the pixel electrodes covers at least one of the first branches, and each of the first branches is disposed in response to one of the patterns.
2. The thin film transistor array of claim 1, further comprising a plurality of top electrodes, wherein each of the top electrodes is disposed between the pixel electrodes and the common lines, and a part of the top electrodes is electrically connected to one of the pixel electrodes.
3. The thin film transistor array of claim 1, wherein each of the common lines further comprises at least a second branch, and the second branch is disposed adjacent to an edge of the pixels.
4. The thin film transistor array of claim 3, wherein the second branch is disposed in response to a plurality of black matrixes of the color filter.
5. The thin film transistor array of claim 1, further comprising a gate insulator disposed over the substrate and covering the common lines.
6. The thin film transistor array of claim 1, further comprising a protection layer over the substrate and covering the data lines.
7. The thin film transistor array of claim 1, wherein the pixel electrodes have at least one second slit.
8. The thin film transistor array of claim 7, wherein the first branches are disposed away from the second slit.
9. A liquid crystal display panel, comprising:
- a color filter having a plurality of patterns;
 - a thin film transistor array, comprising:
 - a substrate;
 - a plurality of scan lines disposed over the substrate;
 - a plurality of data lines disposed over the substrate, wherein a plurality of pixels are defined by the scan lines and the data lines;
 - a plurality of thin film transistors disposed over the substrate, wherein each of the thin film transistors is disposed in one of the pixels;
 - a plurality of pixel electrodes disposed over the substrate, wherein each of the pixel electrodes is disposed in one of the pixels and electrically connected in response to one of the thin film transistors;
 - a plurality of common lines disposed over the substrate, wherein each of the common lines is disposed between two adjacent scan lines, each of the common lines comprising a plurality of first branches, wherein each of the pixel electrodes covers at least one of the first branches, and each of the first branches is disposed in response to one of the patterns; and
 - a liquid crystal layer disposed between the color filter and the thin film transistor array.
10. A capacitor structure for being integrated in a pixel unit, the capacitor structure comprising:
- a substrate;
 - a common line disposed over the substrate, wherein the common line have a plurality of first branches;
 - an gate insulator disposed on the common line; and
 - a pixel electrode disposed over the gate insulator.
11. A capacitor structure of claim 10, further comprising a protection layer disposed between the gate insulator and the pixel electrode.
12. A capacitor structure of claim 11, further comprising a top electrode disposed between the gate insulator and the protection layer, wherein the protection layer has an opening, wherein the top electrode and the pixel electrode is electrically contact via the opening.

* * * * *

专利名称(译)	液晶显示面板，薄膜晶体管阵列和电容器结构		
公开(公告)号	US20060023136A1	公开(公告)日	2006-02-02
申请号	US10/904476	申请日	2004-11-12
[标]申请(专利权)人(译)	赖汉钟离		
申请(专利权)人(译)	LAI HAN-CHUNG		
当前申请(专利权)人(译)	友达光电股份有限公司		
[标]发明人	LAI HAN CHUNG		
发明人	LAI, HAN-CHUNG		
IPC分类号	G02F1/136		
CPC分类号	G02F1/133707 G02F1/1393 G02F1/136213 G02F1/133753		
优先权	093122690 2004-07-29 TW		
其他公开文献	US7362390		
外部链接	Espacenet USPTO		

摘要(译)

提供了一种薄膜晶体管阵列，包括用于提供像素的存储电容的多条公共线。特别地，每条公共线包括多个分支。其中，公共线及其分支和像素电极构成存储电容。分支设置在亮度质量差的像素处。因此，可以在不改变像素的孔径比的情况下增强像素的存储电容。因此，可以提高液晶显示面板的性能。

